AF 765

Docket No.

209291US0

IN RE APPLICATION OF: Hiroyuki NAGASAWA, et al.

SERIAL NO: 09:867,467

May 31, 2001

FILED: FOR:

METHOD OF MANUFACTURING SILICON CARBIDE, SILICON CARBIDE, COMPOSITE MATERIAL,

AND SEMICONDUCTOR ELEMENT

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313 Oorres. and Mail AKCELLES OF THE SERVICE OF THE SERVI

SIR:

Transmitted herewith is an Amendment under 37 CFR 1.116 in the above-identified application.

- No additional fee is required
- ☐ Small entity status of this application under 37 C.F.R. §1.9 and §1.27 is claimed.
- ☐ Additional documents filed herewith:

The Fee has been calculated as shown below:

CLAIMS	CLAIMS REMAINING		HIGHEST NUMBER PREVIOUSLY PAID	NO. EXTRA CLAIMS		RATE		CALCULATIONS
TOTAL	18	MINUS	20	0	х	\$18	=	\$0.00
INDEPENDENT	3	MINUS	3	0	х	\$84	=	\$0.00
	☐ MULTIPLE DEPENDENT CLAIMS + \$280				=	\$0.00		
		TOTAL OF ABOVE CALCULATIONS					\$0.00	
□ Reduction by 50% for filing by Small Entity □ Recordation of Assignment + \$40						\$0.00		
					=	\$0.00		
						TOT	ΓAL	\$0.00

	Α	check	in t	the	amount	of	\$0.00	is	attached	
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- ☐ Credit card payment form is attached to cover the fees in the amount of **§0.00**
- Please charge any additional Fees for the papers being filed herewith and for which no check or credit card payment form is enclosed herewith, or credit any overpayment to deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.
- If these papers are not considered timely filed by the Patent and Trademark Office, then a petition is hereby made under 37 C.F.R. §1.136, and any additional fees required under 37 C.F.R. §1.136 for any necessary extension of time may be charged to Deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.

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Appln No. 09/867,467 Reply to the final Office Action of June 5, 2003

Appln No. 09/867,467
Reply to the final Offi

DOCKET NO.: 209291US0

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

: GROUP: 1765

: EXAMINER: M. Song

IN RE APPLICATION OF:

Hiroyuki NAGASAWA et al

SERIAL NO.: 09/867,467

FILED: May 31, 2001

FOR: METHOD OF MANUFACTURING SILICON CARBIDE,

SILICON CARBIDE, COMPOSITE MATERIAL,

AND SEMICONDUCTOR ELEMENT

AMENDMENT UNDER 37 CFR 1.116

COMMISSIONER FOR PATENTS ALEXANDRIA, VA. 222313

SIR:

Responsive to the Official Action dated June 5, 2003, please amend the above-identified application as follows.

Amendments to the specification begin on page 2 of this paper.

Amendments to the claims begin on page 7 of this paper.

Remarks/comments begin on page 11 of this paper.

RECEIVED TO 1700